

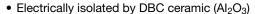
# Thyristor/Thyristor, 150 A (INT-A-PAK Power Module)



**INT-A-PAK** 

| PRIMARY CHARACTERISTICS |                               |  |  |  |
|-------------------------|-------------------------------|--|--|--|
| I <sub>T(AV)</sub>      | 150 A                         |  |  |  |
| Туре                    | Modules - thyristor, standard |  |  |  |
| Package                 | INT-A-PAK                     |  |  |  |

#### **FEATURES**





3500 V<sub>RMS</sub> isolating voltage

- THINS ISSIAMING VOILAGE
- Industrial standard package
- High surge capability
- · Glass passivated chips
- Simple mounting
- UL approved file E78996
- Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **APPLICATIONS**

- · Battery charges
- Welders
- Power converters

| MAJOR RATINGS AND CHARACTERISTICS  |                 |             |                   |  |  |  |  |  |
|------------------------------------|-----------------|-------------|-------------------|--|--|--|--|--|
| SYMBOL                             | CHARACTERISTICS | VALUES      | UNITS             |  |  |  |  |  |
| I <sub>T(AV)</sub>                 | 85 °C           | 150         | A                 |  |  |  |  |  |
| I <sub>T(RMS)</sub>                |                 | 330         |                   |  |  |  |  |  |
| 1                                  | 50 Hz           | 4000        | Α                 |  |  |  |  |  |
| ITSM                               | 60 Hz           | 4200        |                   |  |  |  |  |  |
| 2t                                 | 50 Hz           | 80          | kA <sup>2</sup> s |  |  |  |  |  |
| 1-1                                | 60 Hz           | 73          | KA-S              |  |  |  |  |  |
| I <sup>2</sup> √t                  |                 | 800         | kA²√s             |  |  |  |  |  |
| V <sub>DRM</sub> /V <sub>RRM</sub> |                 | 400         | V                 |  |  |  |  |  |
| T <sub>Stg</sub>                   | Range           | -40 to +150 | °C                |  |  |  |  |  |
| T <sub>J</sub>                     | Range           | -40 to +125 | C                 |  |  |  |  |  |

### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS  |  |  |   |  |  |  |  |
|------------------|--|--|---|--|--|--|--|
| TYPE NUMBER      | V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> /V <sub>DSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> /I <sub>DRM</sub><br>AT 125 °C<br>mA |  |  |  |  |
| VS-VSKT152/04PbF | 400  | 500  | 50  |  |  |  |  |



| ON-STATE CONDUCTION                              |                     |  |  |   |        |                    |
|--|---------------------|--|--|---|--------|--------------------|
| PARAMETER  | SYMBOL              |  | TEST CONDITIO                          | NS  | VALUES | UNITS              |
| Maximum average on-state current                 | I                   | 190° conductio   | on half sine wave                      |   | 150    | Α                  |
| at case temperature                              | I <sub>T(AV)</sub>  | 180 Conductio  | on nan sine wave                       |   | 85     | °C                 |
| Maximum RMS on-state current                     | I <sub>T(RMS)</sub> | As AC switch   |  |   | 330    |                    |
|  |                     | t = 10 ms  | No voltage                             |   | 4000   |                    |
| Maximum peak, one-cycle on-state, non-repetitive |                     | t = 8.3 ms   | reapplied                              |   | 4200   | Α                  |
| surge current                                    | I <sub>TSM</sub>    | t = 10 ms  | 100 % V <sub>RRM</sub>                 |   | 3350   |                    |
| Š  |                     | t = 8.3 ms   | reapplied                              | Sine half wave,                                 | 3500   |                    |
|  |                     | t = 10 ms  | No voltage                             | initial T <sub>J</sub> = T <sub>J</sub> maximum | 80     | kA <sup>2</sup> s  |
| Marrian III for fraince                          | l <sup>2</sup> t    | t = 8.3 ms   | reapplied                              | Ü   | 73     |                    |
| Maximum I <sup>2</sup> t for fusing              | I-r                 | t = 10 ms  | 100 % V <sub>RRM</sub>                 |   | 56     |                    |
|  |                     | t = 8.3 ms   | reapplied                              |   | 51     |                    |
| Maximum I <sup>2</sup> √t for fusing             | I²√t                | t = 0.1 ms to 10                                       | 0 ms, no voltage r                     | eapplied  | 800    | kA <sup>2√</sup> s |
| Value of threshold voltage                       | V <sub>T(TO)</sub>  | T manyimay ma  |  |   | 0.82   | V                  |
| On-state slope resistance                        | r <sub>t</sub>      | T <sub>J</sub> maximum                                 |  | 1.44  | mΩ     |                    |
| Maximum on-state voltage drop                    | $V_{TM}$            | $I_{pk} = \pi \times I_{T(AV)}, T_{J} = 25  ^{\circ}C$ |  |   | 1.48   | V                  |
| Maximum holding current                          | I <sub>H</sub>      |  | ode supply = 6 V,<br>gate open circuit |   | 200    | mA                 |
| Maximum latching current                         | ΙL                  | $T_J = 25$ °C, and                                     | ode supply = 6 V,                      | resistive load                                  | 400    |                    |

| SWITCHING             |                 |   |  |           |       |
|-----------------------|-----------------|---|--|-----------|-------|
| PARAMETER             | SYMBOL          |   | TEST CONDITIONS  | VALUES    | UNITS |
| Typical delay time    | t <sub>gd</sub> | T <sub>J</sub> = 25 °C  | Gate current = 1 A, dl <sub>q</sub> /dt = 1 A/µs                     | 1         |       |
| Typical rise time     | t <sub>gr</sub> | 1J = 25 C   | Gate current = 1 A, $dl_g/dt = 1 A/\mu s$<br>$V_d = 0.67 \% V_{DRM}$ | 2         | μs    |
| Typical turn-off time | t <sub>q</sub>  | $I_{TM} = 300 \text{ A, - dl/dt} = 15 \text{ A/µs; T}_{J} = \text{T}_{J} \text{ maximum}$ $V_{R} = 50 \text{ V; dV/dt} = 20 \text{ V/µs; gate } 0 \text{ V, } 100 \Omega$ |  | 50 to 200 | μο    |

| BLOCKING   |                                       |  |        |       |
|--|---------------------------------------|--|--------|-------|
| PARAMETER  | SYMBOL                                | TEST CONDITIONS  | VALUES | UNITS |
| Maximum peak reverse and off-state leakage current | I <sub>RRM,</sub><br>I <sub>DRM</sub> | T <sub>J</sub> = 125 °C                                  | 50     | mA    |
| RMS insulation voltage                             | V <sub>INS</sub>                      | 50 Hz, circuit to base, all terminals shorted, t = 1 s   | 3500   | V     |
| Critical rate of rise of off-state voltage         | dV/dt                                 | $T_J = T_J$ maximum, exponential to 67 % rated $V_{DRM}$ | 1000   | V/µs  |



| TRIGGERING                                     |                    |   |                                      |        |       |
|--|--------------------|---|--------------------------------------|--------|-------|
| PARAMETER                                      | SYMBOL             | TEST CON  | IDITIONS                             | VALUES | UNITS |
| Maximum peak gate power                        | P <sub>GM</sub>    | $t_p \le 5 \text{ ms}, T_J = T_J \text{ maxim}$                 | um                                   | 12     | W     |
| Maximum average gate power                     | P <sub>G(AV)</sub> | $f = 50 \text{ Hz}, T_J = T_J \text{ maxim}$                    | um                                   | 3      | VV    |
| Maximum peak gate current                      | I <sub>GM</sub>    |   |                                      | 3      | А     |
| Maximum peak negative gate voltage             | - V <sub>GT</sub>  | $t_p \le 5$ ms, $T_J = T_J$ maxim                               | um                                   | 10     |       |
|  |                    | T <sub>J</sub> = - 40 °C  |                                      | 4      | V     |
| Maximum required DC gate voltage to trigger    | $V_{GT}$           | T <sub>J</sub> = 25 °C  |                                      | 2.5    |       |
| voltage to trigger                             |                    | T <sub>J</sub> = T <sub>J</sub> maximum                         | Anode supply = 6 V,                  | 1.7    |       |
|  |                    | $T_J = -40  ^{\circ}\text{C}$ resistive load; $R_a = 1  \Omega$ |                                      | 270    |       |
| Maximum required DC gate<br>current to trigger | I <sub>GT</sub>    | T <sub>J</sub> = 25 °C  |                                      | 150    | mA    |
|  |                    | $T_J = T_J$ maximum   |                                      | 80     |       |
| Maximum gate voltage that will not trigger     | $V_{GD}$           | T - T maximum rated   | V applied                            | 0.3    | V     |
| Maximum gate current that will not trigger     | I <sub>GD</sub>    | $T_J = T_J$ maximum, rated $V_{DRM}$ applied                    |                                      | 10     | mA    |
| Maximum rate of rise of turned-on current      | dl/dt              | $T_J = T_J$ maximum, $I_{TM} = 4$                               | 100 A rated V <sub>DRM</sub> applied | 300    | A/μs  |

| THERMAL AND MECHANICAL SPECIFICATIONS                     |                   |   |             |       |  |  |  |
|---|-------------------|---|-------------|-------|--|--|--|
| PARAMETER   | SYMBOL            | TEST CONDITIONS   | VALUES      | UNITS |  |  |  |
| Maximum junction operating temperature range              | T <sub>J</sub>    |   | -40 to +125 | °C    |  |  |  |
| Maximum storage temperature range                         | T <sub>Stg</sub>  |   | -40 to +150 | O     |  |  |  |
| Maximum thermal resistance, junction to case per junction | R <sub>thJC</sub> | DC operation  | 0.18        | K/W   |  |  |  |
| Maximum thermal resistance, case to heatsink per module   | R <sub>thCS</sub> | Mounting surface smooth, flat and greased   | 0.05        | r/vv  |  |  |  |
| Mounting IAP to heatsink busbar to IAP                    |                   | A mounting compound is recommended and the torque should be rechecked after a period of | 4 to 6      | Nm    |  |  |  |
| Approximate weight  |                   | 3 hours to allow for the spread of the compound.  | 200         | g     |  |  |  |
| Approximate weight  |                   | Lubricated threads.   | 7.1         | OZ.   |  |  |  |
| Case style  |                   |   | INT-A-      | PAK   |  |  |  |

| ∆R CONDUCTI   | ON PE  | R JUNC | CTION |       |       |   |       |       |       |       |       |
|---------------|--|--------|-------|-------|-------|---|-------|-------|-------|-------|-------|
| DEVICES       | SINUSOIDAL CONDUCTION<br>AT T <sub>J</sub> MAXIMUM |        |       |       | I     | RECTANGULAR CONDUCTION<br>AT T <sub>J</sub> MAXIMUM |       |       |       | N     | UNITS |
|               | 180°   | 120°   | 90°   | 60°   | 30°   | 180°  | 120°  | 90°   | 60°   | 30°   |       |
| VSKT152/04PbF | 0.007  | 0.010  | 0.013 | 0.016 | 0.017 | 0.009   | 0.012 | 0.014 | 0.016 | 0.017 | K/W   |

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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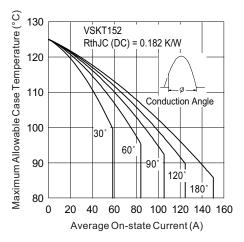


Fig. 1 - Current Ratings Characteristics

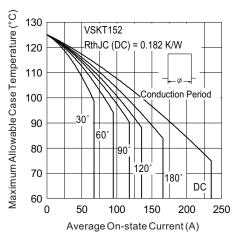


Fig. 2 - Current Ratings Characteristics

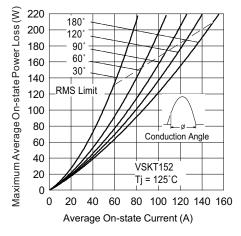


Fig. 3 - Forward Power Loss Characteristics

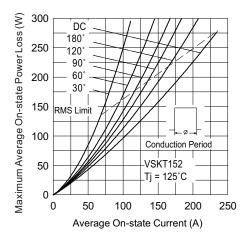


Fig. 4 - Forward Power Loss Characteristics

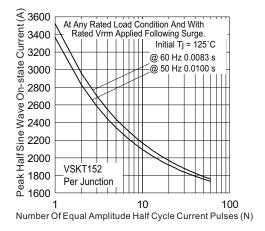


Fig. 5 - Maximum Non-Repetitive Surge Current

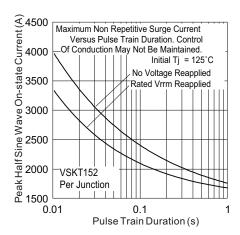


Fig. 6 - Maximum Non-Repetitive Surge Current

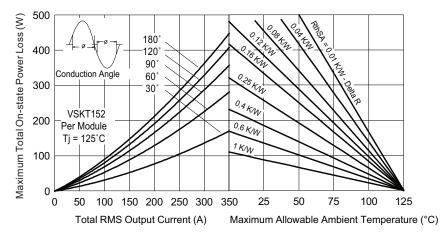


Fig. 7 - On-State Power Loss Characteristics

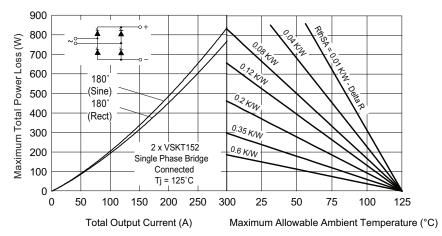


Fig. 8 - On-State Power Loss Characteristics

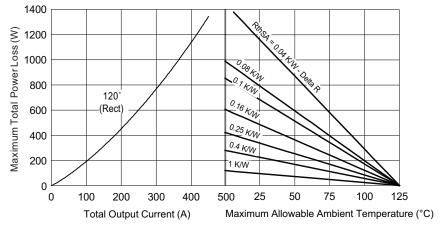


Fig. 9 - On-State Power Loss Characteristics

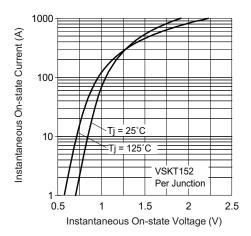


Fig. 10 - On-State Voltage Drop Characteristics

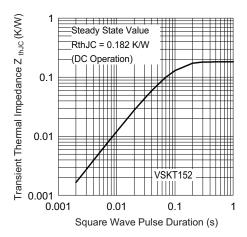


Fig. 11 - Thermal Impedance ZthJC Characteristics

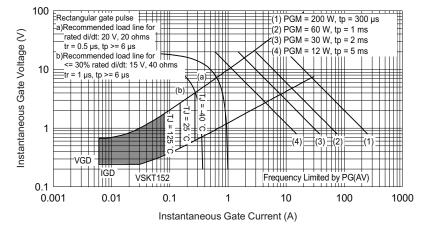
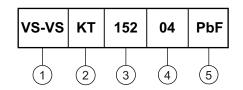


Fig. 12 - Gate Characteristics



#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

Circuit configuration

3 - Current rating

4 - Voltage rating (04 = 400 V)

5 - PbF = Lead (Pb)-free

#### Note

• To order the optional hardware go to <a href="www.vishay.com/doc?95172">www.vishay.com/doc?95172</a>

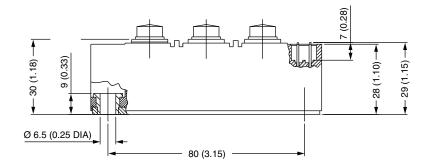
| CIRCUIT CONFIGURATION    |                            |   |  |  |  |  |  |
|--------------------------|----------------------------|---|--|--|--|--|--|
| CIRCUIT DESCRIPTION      | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING   |  |  |  |  |  |
| Two SCRs doubler circuit | Т                          | 10~<br>20+<br>NO 100 100 100 100 100 100 100 100 100 10 |  |  |  |  |  |

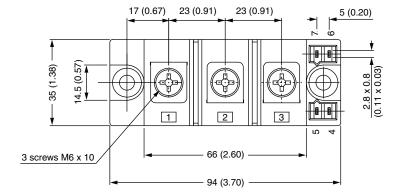
| LINKS TO REL | ATED DOCUMENTS           |
|--------------|--------------------------|
| Dimensions   | www.vishay.com/doc?95067 |

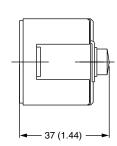


# **INT-A-PAK IGBT/Thyristor**

## **DIMENSIONS** in millimeters (inches)









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